TOSHIBA CCD Linear Image Sensor    CCD (Charge Coupled Device)

TCD1103GFG
The TCD1103GFG is a high sensitive and low dark current 1500 elements CCD linear image sensor.
This device consists of sensitivity CCD chip.
The TCD1103GFG has electronic shutter function (ICG).
Electronic shutter function can keep always output voltage constant that vary with intensity of lights.

Features

- Number of Image Sensing Elements: 1500 elements
- Image Sensing Element Size: 5.5 \( \mu \)m by 64 \( \mu \)m on 5.5 \( \mu \)m center
- Photo Sensing Region: High sensitive PN photodiode
- Power Supply Voltage: 3.0 V (min)
- Internal Circuit: CCD drive circuit
- Package: 16 pin GLCC
- Function: Electronic shutter, Sample and hold circuit

ABSOLUTE MAXIMUM RATINGS (Note 1)

<table>
<thead>
<tr>
<th>Characteristic</th>
<th>Symbol</th>
<th>Rating</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Master clock pulse voltage</td>
<td>( V_M )</td>
<td>-0.3 to +7.0</td>
<td>V</td>
</tr>
<tr>
<td>Shift pulse voltage</td>
<td>( V_{SH} )</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Integration clear pulse voltage</td>
<td>( V_{ICG} )</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Digital power supply voltage</td>
<td>( V_{DD} )</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Analog power supply voltage</td>
<td>( V_{AD} )</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Operating temperature</td>
<td>( T_{opr} )</td>
<td>-25 to +60</td>
<td>°C</td>
</tr>
<tr>
<td>Storage temperature</td>
<td>( T_{stg} )</td>
<td>-40 to +85</td>
<td>°C</td>
</tr>
</tbody>
</table>

Note 1: None of the ABSOLUTE MAXIMUM RATINGS must be exceeded, even instantaneously.
If any one of the ABSOLUTE MAXIMUM RATINGS is exceeded, the electrical characteristics, reliability and life time of the device cannot be guaranteed. If the ABSOLUTE MAXIMUM RATINGS are exceeded, the device can be permanently damaged or degraded.
Create a system design in such a manner that any of the ABSOLUTE MAXIMUM RATINGS will not be exceeded under any circumstances.
Circuit Diagram

<table>
<thead>
<tr>
<th>Pin No.</th>
<th>Symbol</th>
<th>Name</th>
<th>Pin No.</th>
<th>Symbol</th>
<th>Name</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>OS</td>
<td>Output signal</td>
<td>16</td>
<td>NC</td>
<td>Non connection</td>
</tr>
<tr>
<td>2</td>
<td>SS</td>
<td>Ground</td>
<td>15</td>
<td>NC</td>
<td>Non connection</td>
</tr>
<tr>
<td>3</td>
<td>V_{AD}</td>
<td>Power supply (Analog)</td>
<td>14</td>
<td>NC</td>
<td>Non connection</td>
</tr>
<tr>
<td>4</td>
<td>V_{DD}</td>
<td>Power supply (Digital)</td>
<td>13</td>
<td>NC</td>
<td>Non connection</td>
</tr>
<tr>
<td>5</td>
<td>M</td>
<td>Master clock</td>
<td>12</td>
<td>NC</td>
<td>Non connection</td>
</tr>
<tr>
<td>6</td>
<td>ICG</td>
<td>Integration clear gate</td>
<td>11</td>
<td>NC</td>
<td>Non connection</td>
</tr>
<tr>
<td>7</td>
<td>SH</td>
<td>Shift gate</td>
<td>10</td>
<td>NC</td>
<td>Non connection</td>
</tr>
<tr>
<td>8</td>
<td>NC</td>
<td>Non connection</td>
<td>9</td>
<td>NC</td>
<td>Non connection</td>
</tr>
</tbody>
</table>
Optical/Electrical Characteristics
Ta = 25°C, VAD = VDD = 3.3 V, VΦ = 3.3 V (pulse), fM = 2.0 MHz (data rate = 1.0 MHz),
tINT (integration time) = 10 ms, light source = daylight fluorescent lamp

<table>
<thead>
<tr>
<th>Characteristics</th>
<th>Symbol</th>
<th>Min</th>
<th>Typ.</th>
<th>Max</th>
<th>Unit</th>
<th>Note</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sensitivity</td>
<td>R</td>
<td>55</td>
<td>79</td>
<td>—</td>
<td>V/lx·s</td>
<td>(Note 2)</td>
</tr>
<tr>
<td>Photo response non uniformity</td>
<td>PRNU</td>
<td>—</td>
<td>—</td>
<td>10</td>
<td>%</td>
<td>(Note 3)</td>
</tr>
<tr>
<td>Register imbalance</td>
<td>RI</td>
<td>—</td>
<td>1.5</td>
<td>3.0</td>
<td>%</td>
<td>(Note 4)</td>
</tr>
<tr>
<td>Saturation output voltage</td>
<td>V SAT</td>
<td>450</td>
<td>900</td>
<td>—</td>
<td>mV</td>
<td>(Note 5)</td>
</tr>
<tr>
<td>Saturation exposure</td>
<td>SE</td>
<td>—</td>
<td>0.008</td>
<td>—</td>
<td>lx·s</td>
<td>(Note 6)</td>
</tr>
<tr>
<td>Dark signal voltage</td>
<td>V MK</td>
<td>—</td>
<td>3</td>
<td>15</td>
<td>mV</td>
<td>(Note 7)</td>
</tr>
<tr>
<td>DC power dissipation</td>
<td>P D</td>
<td>—</td>
<td>16</td>
<td>48</td>
<td>mW</td>
<td>—</td>
</tr>
<tr>
<td>Total transfer efficiency</td>
<td>TTE</td>
<td>92</td>
<td>95</td>
<td>—</td>
<td>%</td>
<td>—</td>
</tr>
<tr>
<td>Output impedance</td>
<td>Z O</td>
<td>—</td>
<td>0.5</td>
<td>1.0</td>
<td>kΩ</td>
<td>—</td>
</tr>
<tr>
<td>DC output signal voltage</td>
<td>V OS</td>
<td>1.0</td>
<td>1.5</td>
<td>2.0</td>
<td>V</td>
<td>(Note 8)</td>
</tr>
<tr>
<td>Dynamic range</td>
<td>DR</td>
<td>—</td>
<td>200</td>
<td>—</td>
<td>—</td>
<td>(Note 9)</td>
</tr>
</tbody>
</table>

Note 2: Sensitivity is defined for signal outputs average when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

Note 3: PRNU is defined for a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature, where measured approximately 500 mV of signal output.

\[
PRNU = \frac{\Delta X}{X} \times 100 \text{ (%)}
\]

\(\bar{X}\): Average of total signal outputs
\(\Delta X\): The maximum deviation from \(\bar{X}\)

Note 4: Register imbalance is defined as follows.

\[
RI = \frac{\Delta Y - \Delta Z}{X} \times 100 \text{ (%)}
\]

\(\bar{X}\): Average of total signal outputs
\(\Delta Y\): average of odd effective signal outputs – average of even effective signal outputs
\(\Delta Z\): average of odd dummy signal outputs – average of even dummy signal outputs

Note 5: \(V_{SAT}\) is defined as the minimum saturation output voltage of all effective pixels.

Note 6: Definition of SE:

\[
SE = \frac{V_{SAT}}{R}
\]
Note 7: $V_{MDK}$ is defined as the maximum dark signal voltage of all effective pixels.

Note 8: DC output signal voltage is defined as follows.

Note 9: Definition of DR:

$$DR = \frac{V_{SAT}}{V_{MDK}}$$

$V_{MDK}$ is proportional to $t_{INT}$ (integration time). So the shorter integration time makes wider dynamic range.
Recommended Operating Conditions (Ta = 25°C)

For best performance, the device should be used within the Recommended Operating Conditions.

<table>
<thead>
<tr>
<th>Characteristics</th>
<th>Symbol</th>
<th>Min</th>
<th>Typ.</th>
<th>Max</th>
<th>Unit</th>
<th>Note</th>
</tr>
</thead>
<tbody>
<tr>
<td>Master clock pulse voltage</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>&quot;H&quot; level</td>
<td>$V_{\Phi M}$</td>
<td>3.0</td>
<td>3.3</td>
<td>4.0</td>
<td>V</td>
<td>(Note 10)</td>
</tr>
<tr>
<td>&quot;L&quot; level</td>
<td></td>
<td>0</td>
<td>0</td>
<td>0.44</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Shift pulse voltage</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>&quot;H&quot; level</td>
<td>$V_{SH}$</td>
<td>3.0</td>
<td>3.3</td>
<td>4.0</td>
<td>V</td>
<td>(Note 10)</td>
</tr>
<tr>
<td>&quot;L&quot; level</td>
<td></td>
<td>0</td>
<td>0</td>
<td>0.44</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Integration clear pulse voltage</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>&quot;H&quot; level</td>
<td>$V_{ICG}$</td>
<td>3.0</td>
<td>3.3</td>
<td>4.0</td>
<td>V</td>
<td>(Note 10)</td>
</tr>
<tr>
<td>&quot;L&quot; level</td>
<td></td>
<td>0</td>
<td>0</td>
<td>0.44</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Power supply voltage (Digital)</td>
<td>$V_{DD}$</td>
<td>3.0</td>
<td>3.3</td>
<td>4.0</td>
<td>V</td>
<td>(Note 11)</td>
</tr>
<tr>
<td>Power supply voltage (Analog)</td>
<td>$V_{AD}$</td>
<td>3.0</td>
<td>3.3</td>
<td>4.0</td>
<td>V</td>
<td>(Note 11)</td>
</tr>
</tbody>
</table>

Note 10: Max voltage of pulse voltage "H" level = $V_{DD} = V_{AD}$
Min voltage of pulse voltage "H" level = $V_{DD} - 0.5 V = V_{AD} - 0.5 V$

Note 11: $V_{AD} = V_{DD}$

Clock Characteristics (Ta = 25°C) (3.0 V ≤ $V_{AD} = V_{DD} ≤ 4.0$ V)

For best performance, the device should be used within the Recommended Operating Conditions.

<table>
<thead>
<tr>
<th>Characteristics</th>
<th>Symbol</th>
<th>Min</th>
<th>Typ.</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Master clock pulse frequency</td>
<td>$f_{\Phi M}$</td>
<td>0.4</td>
<td>2.0</td>
<td>4.0</td>
<td>MHz</td>
</tr>
<tr>
<td>Data rate</td>
<td>$f_{DATA}$</td>
<td>0.2</td>
<td>1.0</td>
<td>2.0</td>
<td>MHz</td>
</tr>
<tr>
<td>Master clock capacitance</td>
<td>$C_{\Phi M}$</td>
<td>—</td>
<td>10</td>
<td>—</td>
<td>pF</td>
</tr>
<tr>
<td>Shift gate capacitance</td>
<td>$C_{SH}$</td>
<td>—</td>
<td>150</td>
<td>—</td>
<td>pF</td>
</tr>
<tr>
<td>Integration clear gate capacitance</td>
<td>$C_{ICG}$</td>
<td>—</td>
<td>35</td>
<td>—</td>
<td>pF</td>
</tr>
</tbody>
</table>
Timing Chart 1

- **t_{INT}** (integration time)

**SH**
- Dummy outputs (16 elements)
- Light shielded outputs (13 elements)
- Dummy outputs (32 elements)

**ICG**
- Effective outputs (1500 elements)

**OS**
- Dummy outputs (14 elements)

1 line readout period (1546 elements)
Timing Chart 2 (Use Electronic Shutter Function)

Readout time

SH

ICG

ϕM

OS

Dummy outputs (16 elements)
Light shielded outputs (13 elements)
Dummy outputs (32 elements)
1 line readout period (1546 elements)
Effective outputs (1500 elements)
Dummy outputs (14 elements)

Dummy outputs (3 elements)
Timing Requirements

![Waveform Diagram]

<table>
<thead>
<tr>
<th>Characteristics</th>
<th>Symbol</th>
<th>Min</th>
<th>Typ.</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>ICG pulse delay</td>
<td>t1</td>
<td>1000</td>
<td>5000</td>
<td>—</td>
<td>ns</td>
</tr>
<tr>
<td>Pulse timing of ICG and SH</td>
<td>t2</td>
<td>100</td>
<td>500</td>
<td>1000</td>
<td>ns</td>
</tr>
<tr>
<td>Shift pulse width</td>
<td>t3</td>
<td>1000</td>
<td>—</td>
<td>—</td>
<td>ns</td>
</tr>
<tr>
<td>Pulse timing of ICG and (\phi_M)</td>
<td>t4</td>
<td>0</td>
<td>20</td>
<td>*</td>
<td>ns</td>
</tr>
</tbody>
</table>

* : To keep \(\phi_M\) “H” level when ICG switch from “L” to “H” level.

Use Electronic Shutter

Pulse timing of SH and ICG

![Waveform Diagram]

** : Each SH high pulse have to keep always the same value with “t3 “ (t3 ≥ 1000 ns (min)).

*** : SH pulse cycle have to keep the same cycle (SH cycle period ≥ 10 μs) except tINT period.

**** : tINT ≥ 10 μs (min).

The illumination of light source must be less than 1000 times of the 450 mV output condition at tINT = 10 ms.
Typical Performance Curves

Spectral Response

<table>
<thead>
<tr>
<th>Wavelength [nm]</th>
<th>Relative response</th>
</tr>
</thead>
<tbody>
<tr>
<td>400</td>
<td>1.0</td>
</tr>
<tr>
<td>500</td>
<td>0.8</td>
</tr>
<tr>
<td>600</td>
<td>0.6</td>
</tr>
<tr>
<td>700</td>
<td>0.4</td>
</tr>
<tr>
<td>800</td>
<td>0.2</td>
</tr>
<tr>
<td>900</td>
<td>0.1</td>
</tr>
<tr>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>1100</td>
<td></td>
</tr>
<tr>
<td>1200</td>
<td></td>
</tr>
</tbody>
</table>

Ta = 25°C

Sensitivity Response

<table>
<thead>
<tr>
<th>Power supply VAD, VDD [V]</th>
<th>Sensitivity [V/\mu\text{x}\cdot\text{s}]</th>
</tr>
</thead>
<tbody>
<tr>
<td>3</td>
<td>50</td>
</tr>
<tr>
<td>3.3</td>
<td>60</td>
</tr>
<tr>
<td>3.6</td>
<td>70</td>
</tr>
<tr>
<td>3.9</td>
<td>80</td>
</tr>
<tr>
<td>4.0</td>
<td>90</td>
</tr>
</tbody>
</table>

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Typical Performance Curves

DC Output Signal Voltage – Power Supply Voltage

DC output signal voltage Vos [V]

Power supply VAD, VDD [V]

0 1 2 3 3.3 3.6 3.9

0 1 2 3

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Rev.1.2 2019-01-24
Typical Drive Circuit

IC1 : 74HC04

3.3 V

10 μF/25 V

0.1 μF/25 V

SH

ICG

φM

IC1

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Cautions

1. **Electrostatic Breakdown**

   Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

   CCD Image Sensor is protected against static electricity, but inferior puncture mode device due to static electricity is sometimes detected. In handing the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

   a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.
   b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.
   c. Ground the tools such as cutting pliers, tweezers or pincer.
   d. When the product is handed, please use tweezers to avoid the damage of CCD image sensor.
   e. Ionized air is recommended for discharge when handling CCD image sensors.

   It is not necessarily required to execute all precaution items for static electricity. It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.

2. **Incident Light**

   CCD sensor is sensitive to infrared light. Note that infrared light component degrades resolution and PRNU of CCD sensor.

3. **Ultrasonic Cleaning**

   Ultrasonic cleaning should not be used with such hermetically-sealed ceramic package as CCD because the bonding wires can become disconnected due to resonance during the cleaning process.

4. **Window Glass**

   The dust and stain on the glass window of the package degrade optical performance of CCD sensor. Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N₂. Care should be taken to avoid mechanical or thermal shock because the glass window is easily to damage.
5. **Cleaning Method of the Window Glass Surface**

**Wiping Cloth**
- Use soft cloth with a fine mesh.
- The wiping cloth must not cause dust from itself.
- Use a clean wiping cloth necessarily.

**Cleaner**
When using solvents, such as alcohol, unavoidably, it is cautious of the next.
- A clean thing with quick-drying.
- After liquid dries, there needs to be no residual substance.
- A thing safe for a human body.

And, please observe the use term of a solvent and use the storage container of a solvent to be clean.

Be cautious of fire enough.

**Way of Cleaning**

First, the surface of window glass is wiped with the wiping cloth into which the cleaner was infiltrated. Please wipe down the surface of window glass at least 2 times or more.

Next, the surface of window glass wipes with the dry wiping cloth. Please wipe down the surface of window glass at least 3 times or more.

Finally, blow cleaning is performed by dry N2 filtered.

If operator wipes the surface of the window glass with the above-mentioned process and dirt still remains, TOSHIBA recommends repeating the clean operation from the beginning.

Be cautious of the next thing.
- Don’t infiltrate the cleaner too much.
- A wiping portion is performed into the optical range and don't touch the edge of window glass.
- Be sure to wipe in a long direction and the same direction.
- A wiping cloth always uses an unused portion.
The Standard Reflow Condition for GLCC (Surface Mount Device)

1. Storage Precautions
   1) CCD surface mount products may have a haze on the inside of glass, so be careful about following. Even if the haze arises inside of glass, when it is not on the pixel area, there is no problem in quality.
   2) Do not drop or toss device packaging. The laminated aluminum material in it can be rendered ineffective by rough handling.
   3) Ensure devices should be stored in a 30°C·90 %RH or better environment. Use devices within 12 months; do not store them longer than that.
   4) In the following cases, in order to remove humidity from a device, bake for 24 hours at 125°C. When a "30 % humidity indicator" has become pink after the package opened, or when the effective period of the indicator has passed.
   5) Prevent destruction of the device by static electricity in the case of the bake processing for removing humidity.
   6) After opening moisture-proof packing, store a product in 30°C·60 %RH or better environment and use them within five days. If the effective usage period passed after opening the moisture-proof packing, baking should be done before use at 125°C for 24 hours.

2. Mounting Conditions Using Reflow
   1) Mounting method: (a) Hot air reflow  
      (b) Infrared ray reflow
   2) Preheating condition: 150 to 180°C, 60 to 120 s
   3) Reflow condition: (a) Maximum 240°C  
      (b) Over 230°C, within 30 to 50 s
   4) Heating times: Only 1 time

* The temperature profile is specified in terms of the temperature of top surface of the device.
This temperature profile shows the maximum guaranteed device temperature. Please set up the optimum temperature profile conditions within the fig.1 profile.

fig.1 Example of recommended temperature profile for reflows

In addition, in case of the repair work accompanied by IC removal, since the degree of parallel may be spoiled with the left solder, please do not carry out.
3. Mounting

1) In the case of solder mounting, the devices should be mounted with the window glass protective tape in order to avoid dust or dirt included in reflow machine.

2) The window glass protective tape is manufactured from materials in which static charges tend to build up. When removing the tape from CCD sensor after solder mounting, install an ionizer to prevent the tape from being charged with static electricity.

3) When the tape is removed, adhesives will remain in the glass surface. Since these adhesives appear as black or white flaws on the image, please wipe the window glass surface with the cloth into which the organic solvent was infiltrated. Then please attach CCD to a product.

4) Do not reuse the window glass protective tape.

5) The parts of glass seal area have possibility to became clouded by reflow process, however, there is no problem in quality.

4. Foot Pattern on the PCB

We recommend fig.2’s foot pattern for your PCB (Printed Circuit Board).

5. Mask for Solder Paste Application

We recommend metal mask that have the following thickness.
- Thickness: 0.1 mm.
And we recommend that the opened area size on the metal mask is 100% for pads on solder.
Package Dimensions

WQFN16X-240B

Unit: mm

Note 1: Distance between the edge of the package and the first pixel (S1)
Note 2: Distance between the top of chip and bottom of the package
Note 3: Distance between the edge of the package and the chip center
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